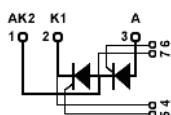


STT27GKxx

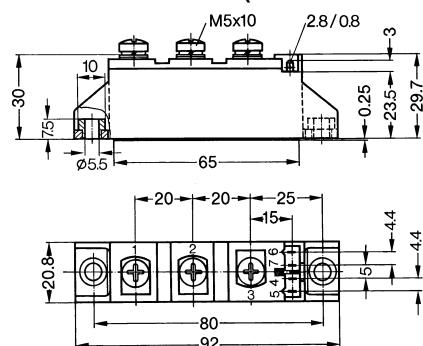
Thyristor-Thyristor Modules



Type	V_{RSM} V_{DSM}	V_{RRM} V_{DRM}
	V	V
STT27GK08	900	800
STT27GK12	1300	1200
STT27GK14	1500	1400
STT27GK16	1700	1600

Tolerance: $\pm 0.5\text{mm}$

Dimensions in mm (1mm=0.0394")



Symbol	Test Conditions	Maximum Ratings	Unit
I_{TRMS}, I_{FRMS} I_{TAVM}, I_{FAVM}	$T_{VJ}=T_{VJM}$ $T_c=85^\circ\text{C}; 180^\circ \text{ sine}$	50 27	A
I_{TSM}, I_{FSM}	$T_{VJ}=45^\circ\text{C}$ $V_R=0$	520 560	A
	$T_{VJ}=T_{VJM}$ $V_R=0$	460 500	
$\int i^2 dt$	$T_{VJ}=45^\circ\text{C}$ $V_R=0$	1350 1300	A^2s
	$T_{VJ}=T_{VJM}$ $V_R=0$	1050 1030	
$(di/dt)_{cr}$	$T_{VJ}=T_{VJM}$ $f=50\text{Hz}, t_p=200\mu\text{s}$ $V_D=2/3V_{DRM}$ $I_G=0.45\text{A}$ $dI/dt=0.45\text{A}/\mu\text{s}$	150 500	$\text{A}/\mu\text{s}$
	$V_{DR}=2/3V_{DRM}$ $R_{GK}=\infty$; method 1 (linear voltage rise)	1000	
P_{GM}	$T_{VJ}=T_{VJM}$ $t_p=30\mu\text{s}$ $I_T=I_{TAVM}$ $t_p=300\mu\text{s}$	10 5	W
P_{GAV}		0.5	W
V_{RGM}		10	V
T_{VJ} T_{VJM} T_{stg}		-40...+125 125 -40...+125	$^\circ\text{C}$
V_{ISOL}	50/60Hz, RMS $I_{ISOL}\leq 1\text{mA}$	3000 3600	$\text{V}\sim$
M_d	Mounting torque (M5) Terminal connection torque (M5)	2.5-4.0/22-35 2.5-4.0/22-35	Nm/lb.in.
Weight	Typ.	81	g

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Thyristor-Thyristor Modules

Symbol	Test Conditions	Characteristic Values	Unit
I_{RRM}, I_{DRM}	$V_{VJ}=V_{VJM}$; $V_R=V_{RRM}$; $V_D=V_{DRM}$	3	mA
V_T, V_F	$I_T, I_F=80A$; $T_{VJ}=25^\circ C$	1.64	V
V_{TO}	For power-loss calculations only ($T_{VJ}=125^\circ C$)	0.85	V
R_T		11	$m\Omega$
V_{GT}	$V_D=6V$; $T_{VJ}=25^\circ C$ $T_{VJ}=-40^\circ C$	1.5 1.6	V
I_{GT}	$V_D=6V$; $T_{VJ}=25^\circ C$ $T_{VJ}=-40^\circ C$	100 200	mA
V_{GD}	$T_{VJ}=T_{VJM}$; $V_D=2/3V_{DRM}$	0.2	V
I_{GD}		10	mA
I_L	$T_{VJ}=25^\circ C$; $t_p=10\mu s$; $V_D=6V$ $I_G=0.45A$; $dI/dt=0.45A/\mu s$	450	mA
I_H	$T_{VJ}=25^\circ C$; $V_D=6V$; $R_{GK}=\infty$	200	mA
t_{gd}	$T_{VJ}=25^\circ C$; $V_D=1/2V_{DRM}$ $I_G=0.45A$; $dI/dt=0.45A/\mu s$	2	us
t_q	$T_{VJ}=T_{VJM}$; $I_T=20A$; $t_p=200\mu s$; $-dI/dt=10A/\mu s$ $V_R=100V$; $dV/dt=20V/\mu s$; $V_D=2/3V_{DRM}$	typ. 150	us
Q_s	$T_{VJ}=T_{VJM}$; $I_T, I_F=25A$; $-dI/dt=0.64A/\mu s$	50	uC
I_{RM}		6	A
R_{thJC}	per thyristor/diode; DC current per module	0.88 0.44	K/W
R_{thJK}	per thyristor/diode; DC current per module	1.08 0.54	K/W
ds	Creeping distance on surface	12.7	mm
d_A	Strike distance through air	9.6	mm
a	Maximum allowable acceleration	50	m/s^2

FEATURES

- * International standard package
- * DCB base plate
- * Glass passivated chips
- * Isolation voltage 3600 V~
- * UL file NO.310749
- * RoHs compliant

APPLICATIONS

- * DC motor control
- * Softstart AC motor controller
- * Light, heat and temperature control

ADVANTAGES

- * Space and weight savings
- * Simple mounting with two screws
- * Improved temperature and power cycling
- * Reduced protection circuits

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Thyristor-Thyristor Modules

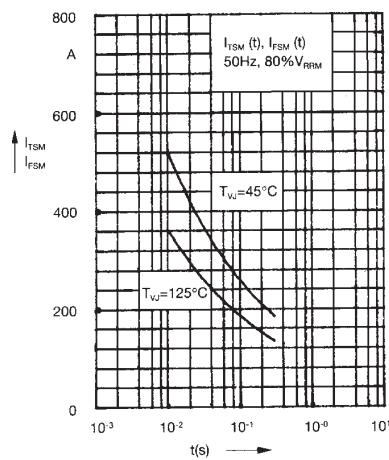


Fig. 1 Surge overload current
 I_{TSM}, I_{FSM} : Crest value, t : duration

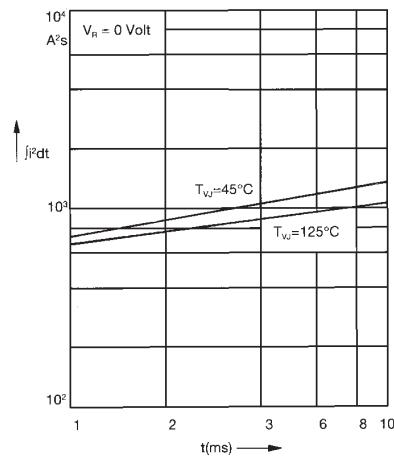


Fig. 2 $\int i^2 dt$ versus time (1-10 ms)

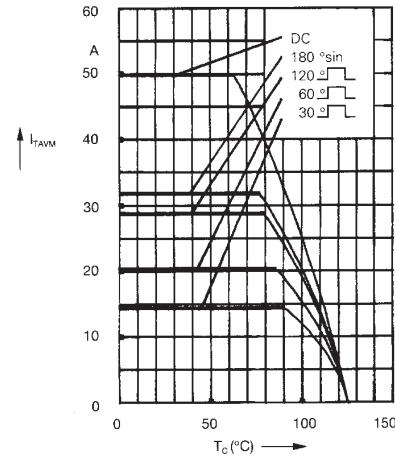


Fig. 2a Maximum forward current
at case temperature

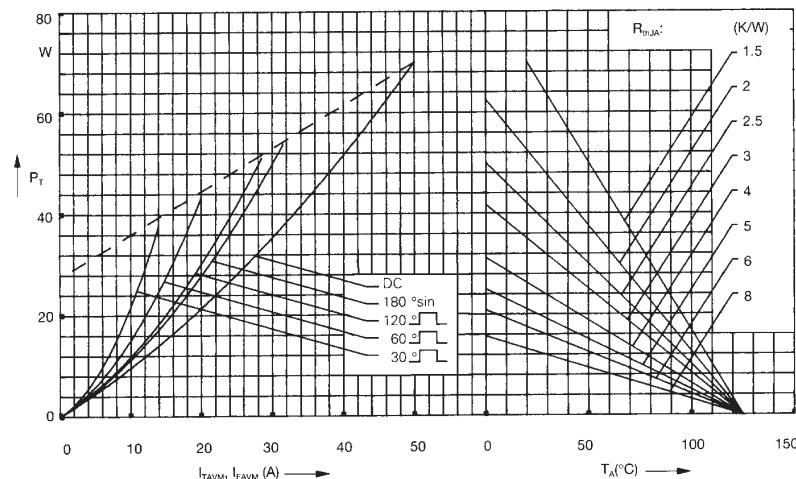


Fig. 3 Power dissipation versus on-state current and ambient temperature
(per thyristor or diode)

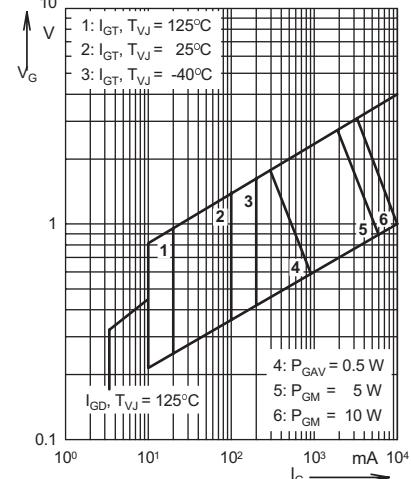


Fig. 4 Gate trigger characteristics

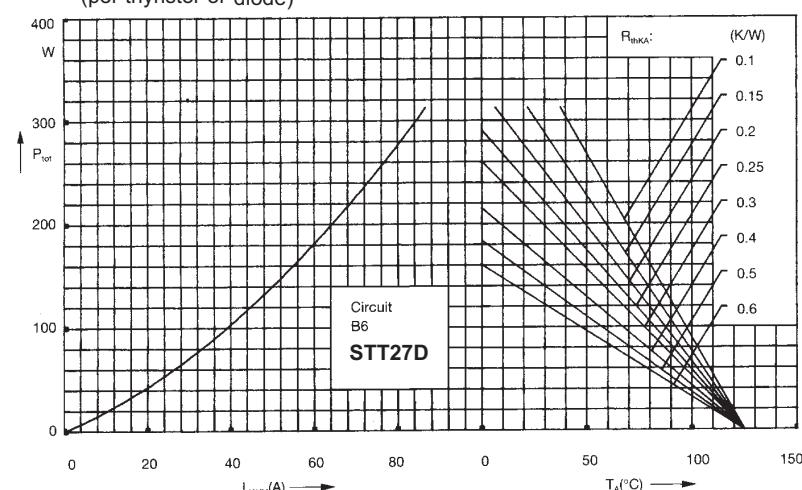


Fig. 5 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

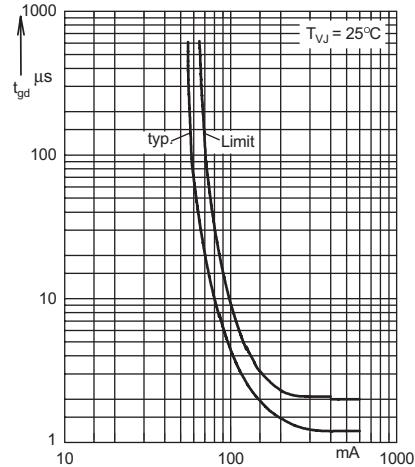


Fig. 6 Gate trigger delay time

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Thyristor-Thyristor Modules

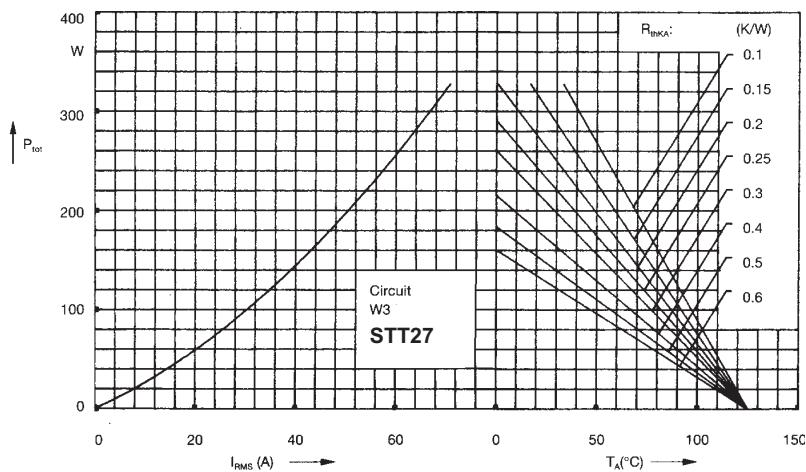


Fig. 7 Three phase AC-controller:
Power dissipation versus RMS
output current and ambient
temperature

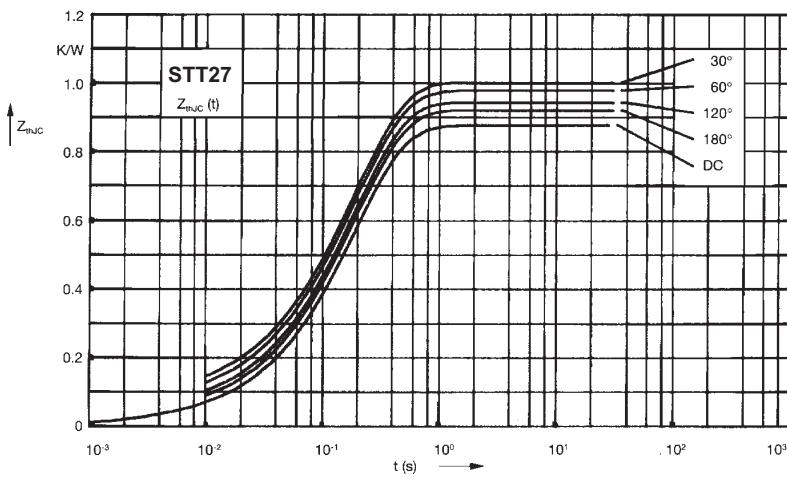


Fig. 8 Transient thermal impedance
junction to case (per thyristor or
diode)

d	R_{thJC} (K/W)
DC	0.88
180°	0.92
120°	0.95
60°	0.98
30°	1.01

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.019	0.0031
2	0.029	0.0216
3	0.832	0.191

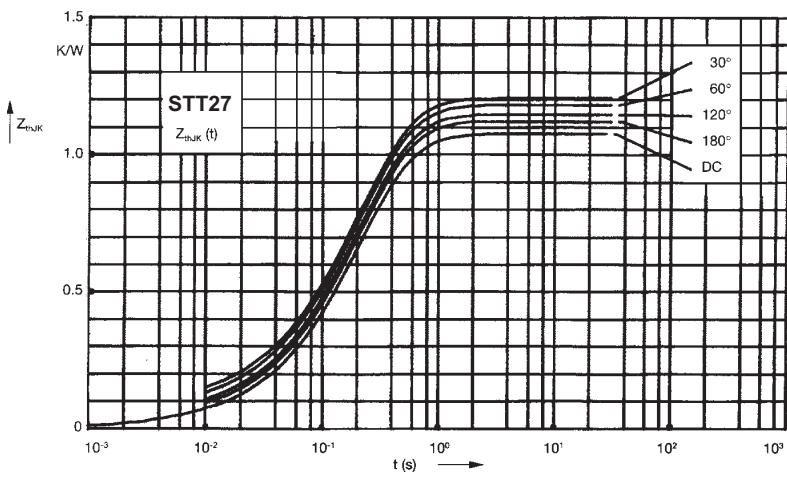


Fig. 9 Transient thermal impedance
junction to heatsink (per thyristor or
diode)

d	R_{thJK} (K/W)
DC	1.08
180°	1.12
120°	1.15
60°	1.18
30°	1.21

Constants for Z_{thJK} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.019	0.0031
2	0.029	0.0216
3	0.832	0.191
4	0.2	0.45